

MAINTENANCE MANUAL

138-174 MHz RF ASSEMBLY 19D416693G1, G2, G7, G8

AND MIXER/IF BOARDS 19C320153G1/19C331099G1, G2

TABLE OF CONTENTS	
	Page
DESCRIPTION	Front Cover
CIRCUIT ANALYSIS	Front Cover
PARTS LIST	1
PRODUCTION CHANGES	2
OUTLINE DIAGRAM	4
SCHEMATIC DIAGRAMS	
RF Assembly	3
Mixer/IF Board	5

DESCRIPTION

The RF Assembly uses five tuned helical resonators to provide front end RF selectivity with no gain. A UHF pre-amplifier assembly is available that can be used with the receiver to improve sensitivity.

The Mixer/IF board (MIF) uses the RF signal from the RF Assembly and the mixer injection from the oscillator board to generate the IF frequency.

CIRCUIT ANALYSIS

RF ASSEMBLY

RF Pre-amplifier (Optional)

The pre-amplifier is present only in UHF receivers, and uses a dual-gate Field Effect Transistor (FET) to provide approximately 12 dB gain.

RF from the antenna is coupled through T2301 to Gate 1 of pre-amplifier Q2301. The primary of T2301 provides a 50 ohm input impedance. The amplified output at the drain terminal of Q2301 is coupled through T2302 and connected to J1 on Antenna Input board A301 through cable W2302. T2302 is tapped to provide a 50 ohm output impedance. P2301 connects to J501 on the MIF board for the regulated +10 Volt supply voltage.

Antenna Input A301/A301B

An RF signal from the antenna or UHF pre-amplifier is applied to A301 which provides an AC ground between vehicle ground and receiver A-. Resistor R1 prevents a static charge from building up on the vehicle antenna. The output of A301 is coupled through five high Q helical resonators that provide the front end RF selectivity. The helicals are tuned to the incoming frequency by C301 through C305.

MIXER-IF

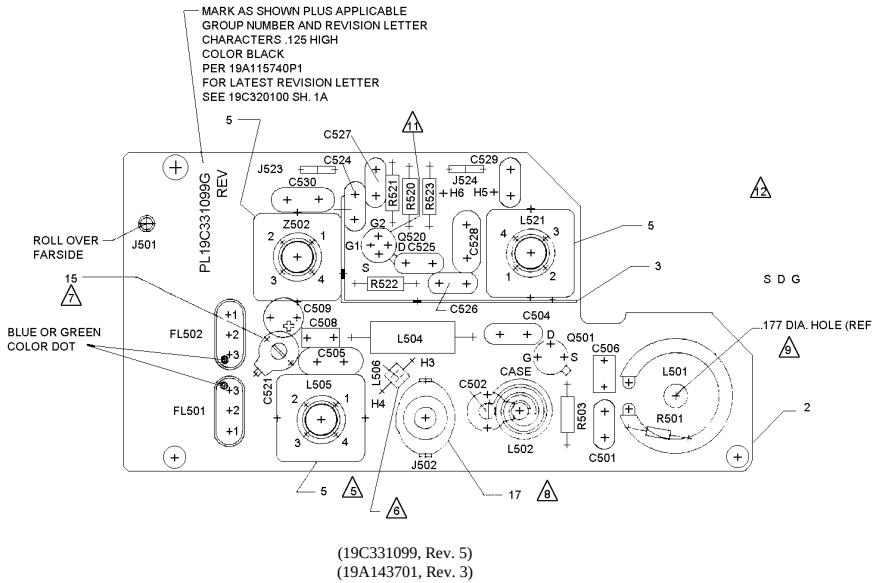
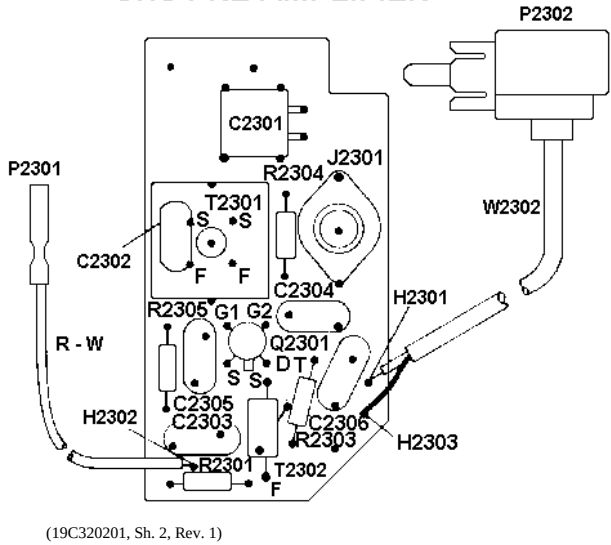
Mixer & Crystal Filter

The mixer uses a FET (Q501) as the active device. The FET mixer provides a high input impedance, high power gain, and an output relatively free of harmonics (low in intermodulation products).

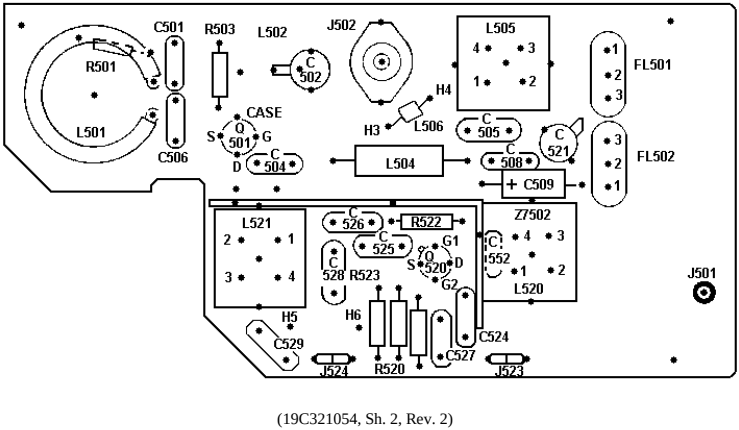
In the mixer stage, RF from the helical resonators is coupled through L502 and C502 which matches the RF output to the gate of mixer Q501. Injection voltage from the multiplier-selectivity stages is inductively coupled through L501 to the source of the mixer. The 11.2 MHz mixer IF (9.4 MHz alternate IF) output signal is coupled from the drain of Q501 through a tuned circuit (L505 and C505) which matches the mixer output to the input of the four-pole monolithic crystal filter. The highly-selective crystal filter (FL501 and FL502) provides the first portion of the receiver IF selectivity. The output of the filter is coupled through impedance-matching network L520 and C523 to the IF amplifier.



UHS PRE-AMPLIFIER

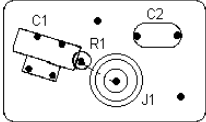


MIXER/IF BOARD
COMPONENT SIDE



A301A
ANT INPUT

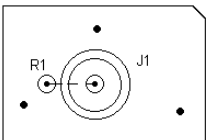
(FLOATING GROUND)



(19B219679, Sh. 2, Rev. 7A)

A301B
ANT INPUT

(NON-FLOATING GROUND)



LEAD IDENTIFICATION
FOR Q501



VIEW FROM LEAD END

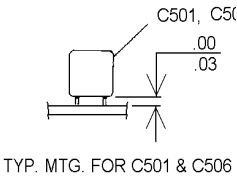
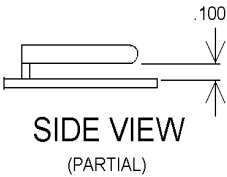
NOTE: LEAD ARRANGEMENT, AND NOT
CASE SHAPE, IS DETERMINING
FACTOR FOR LEAD IDENTIFICATION.

LEAD IDENTIFICATION
FOR Q520

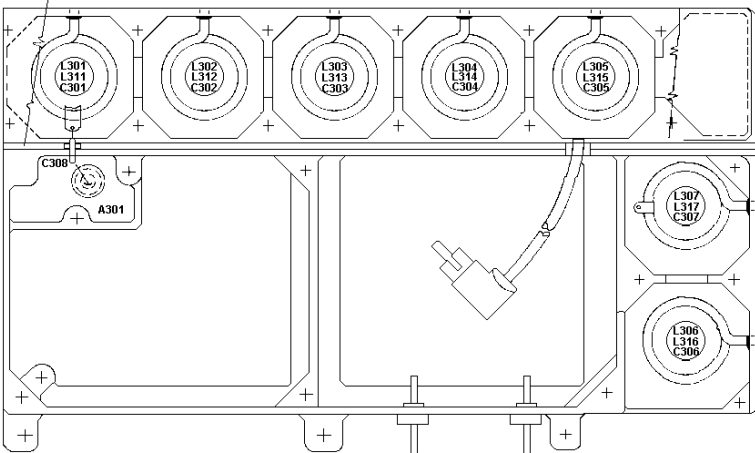


VIEW FROM LEAD END

NOTE: LEAD ARRANGEMENT, AND NOT
CASE SHAPE, IS DETERMINING
FACTOR FOR LEAD IDENTIFICATION.

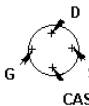


RF ASSEMBLY
BOTTOM VIEW



(19D423618, Rev. 2)

LEAD IDENTIFICATION
FOR Q501

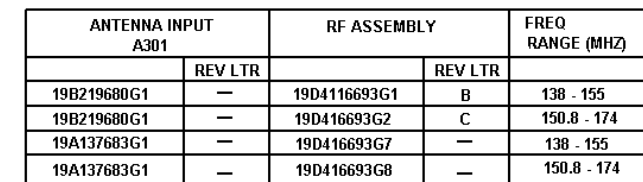


VIEW FROM CASE END

Q520, Q2301



NOTE: LEAD ARRANGEMENT, AND NOT
CASE SHAPE, IS DETERMINING
FACTOR FOR LEAD IDENTIFICATION.



IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

VOLTAGE READINGS ARE TYPICAL READINGS MEASURED TO SYSTEM NEGATIVE (P903-10) WITH TEST SET MODEL 4EX3A11 OR A 20,000 OHM-PER-VOLT METER.

 INDICATES A-
 INDICATED VEHICLE GROUND

(19D423469, Rev. 1)

PARTS LIST LBI4981J 138 - 174 MHz RF ASSEMBLY, MIF ASSEMBLY, UHS PRE - AMPLIFIER		
SYMBOL	PART NO.	DESCRIPTION
A301A		RF ASSEMBLY 19D416693G1 138 - 155 MHz FLOATING GRD 19D416693G2 150.8 - 184 MHz FLOATING GRD 19D416693G7 138 - 155 MHz NON FLOATING GRD 19D416693G8 150.8 - 174 MHz NON FLOATING GRD ANTENNA INPUT BOARD 19B219680G1 - - - - - CAPACITORS - - - - - C1 19A700015P45 Silver mica: 470 pF ± 5%, 250 VDCW. C2 19A700005P7 Polyester: 0.01 uF ± 10%, 50 VDCW. - - - - - JACKS AND RECEPTACLES - - - - - J1 7104941P16 Jack, phono: coaxial. - - - - - RESISTORS - - - - - R1 19A700106P79 Composition: 4.7K ohms ± 5%, 1/4 w. A301B ANTENNA INPUT PLATE 19A137683G1 - - - - - JACKS AND RECEPTACLES - - - - - J1 7104941P20 Jack, phono: coaxial. - - - - - RESISTORS - - - - - R1 19A700106P79 Composition: 4.7K ohms ± 5%, 1/4 w. A302 and A303 COMPONENT BOARD A302 19B226512G1 138 - 155 MHz A303 19B226512G2 150.8 - 174 MHz - - - - - INDUCTORS - - - - - L305 19B216112G20 Coil. L315 19B216112G21 Coil. - - - - - CABLES - - - - - P301 5491689P85 Cable, RF: approx. 4 inches long. - - - - - CAPACITORS - - - - - C301 thru C305 Includes: 19C328755P3 Screw. 19A143476G2 Nut: thd. size No. 8 - 32. C306* and C307* Includes: 19C328755P3 Screw. (Added to G2 by REV C). 4036765G12 Screw. (Deleted in G2 by REV C). 19A143476G2 Nut: thd. size no. 8 - 32. C308 5495681P11 Ceramic disc: 1000 pF ± 20%, 1000 VDCW; sim to RMC Type JR Discap. C325 19B209488P1 Ceramic: 6.8 pF ± 20%, 500 VDCW; sim to Allen Bradley Style FA5D. C326 19B209488P2 Ceramic: 1000 pf - 10 + 100%, 500 VDCW; sim to Allen Bradley Style FA5D. - - - - - CAPACITORS - - - - - L301 19B216112G19 Coil. L302 thru L304 19B216112G11 Coil.
L306 and L307	19B204461G18	Coil.
L311	19B216112G17	Coil.
L312 thru L314	19B216112G15	Coil.
L316 and L317	19B204461G19	Coil.
		- - - - - MISCELLANEOUS - - - - - 19E500969G1 Casting. 19C320251P1 Cover. 19B209209P305 Tap screw, Phillips POZIDRIV®: No. 6 - 32 x 5/16. (Secures cover). 19B201074P304 Tap screw, Phillips POZIDRIV®: No. 6 - 32 x 1/4. (Used with A301 - A303).
		MIF ASSEMBLY 19C320153G1 - - - - - CAPACITORS - - - - - C501 19A116655P19 Ceramic disc: 1000 pF ± 20%, 1000 VDCW; sim to RMC Type JF Discap. C502 19A700012P2 Variable, ceramic: 2.5 to 20 pF 200 VDCW, temp coef - 250 - 700 PPM; sim to Panasonic ECXIZW20X32. C504 19A116656P27K0 Ceramic disc: 27 pF ± 10%, 500 VDCW, temp coef 0 PPM. C505 19A700105P46 Mica: 270 pF ± 5%, 500 VDCW. C506 19A700005P7 Polyester: 0.01 uF ± 10%, 50 VDCW. C508 19A700005P9 Polyester: 0.022 uF ± 10%, 50 VDCW. C509 5496267P10 Tantalum: 22 uF ± 20%, 15 VDCW; sim to Sprague Type 150D. C521 19A700012P1 Variable, ceramic: 2 to 10 pF, 200 VDCW, temp coef - 350 to + 500 PPM; sim to Panasonic ECV - 12W10X32. C523 (Part of Z502). C524 thru C527 Polyester: 0.022 uF ± 20%, 50 VDCW. C528 5490009P139 Silver mica: 330 pF ± 10%, 50 VDCW, sim to Electro Motive Type DM - 15. C529 19A116655P19 Ceramic disc: 1000 pF ± 20%, 1000 VDCW; sim to RMC Type JF Discap. - - - - - FILTERS - - - - - FL501 19B219573G3 Crystal: Resonator A - 11,200,000; Resonator B - 11,196.024 kHz. (Part of FL501). FL502 - - - - - JACKS AND RECEPTACLES - - - - - J501 4033513P1 Contact, electrical: sim to Bead Chain L93 - 4. J502 19A700049P2 Connector, receptacle; 500 VDCW maximum; sim to NTTF - 1058. J523 and J524 19A116975P1 Contact, electrical. - - - - - INDUCTORS - - - - - L501 19A129280P1 Coil. L502 Coil. (Part of printed wire board 19C321054P1) L504 7489079P48 Coil, RF: 27 uH 10%, 1.4 ohms DC res. max; sim to Jeffers 4422 - 9. L505 19C320141P30 Coil. 5493185P9 Tuning slug. L506 19A700103P1 Core toroidal, ferrite. (Part of Z502). L520 19C320141P6 Coil. L521 5493185P9 Tuning slug.

*COMPONENTS ADDED, DELETED OR CHANGED FOR PRODUCTION CHANGES.

SYMBOL	PART NO.	DESCRIPTION	SYMBOL	PART NO.	DESCRIPTION
		- - - - - TRANSISTORS - - - - -			RECEIVER MODIFICATION KIT 19A129750G1
Q501	19A702058P1	N Type, field effect; sim to Type 2N4391.			- - - - - DIODES AND RECTIFIERS - - - - -
Q520	19A116818P4	N Channel, field effect.	CR2301	19A116925P1	Silicon.
		- - - - - RESISTORS - - - - -			- - - - - RESISTORS - - - - -
R501	3R151P471J	Composition: 470 ohms ± 5%, 1/8 w.	R2301	19A700106P95	Composition: 22K ohms ± 5%, 1/4 w.
R503	19A700106P33	Composition: 56 ohms ± 5%, 1/8 w.	R2302	19A700106P59	Composition: 680 ohms ± 5%, 1/4 w.
R520	19A700106P87	Composition: 10K ohms ± 5%, 1/8 w.			- - - - - CABLES - - - - -
R521	19A700106P77	Composition: 3.9Kohms ± 5%, 1/8 w.	W2301	19B219999G2	Cable, RF: approx. 1 foot long. Includes: (1) 5496078P2 connector.
R522	19A700106P47	Composition: 220 ohms ± 5%, 1/8 w.			DFE MODIFICATION KIT 19A129750G2
R523	19A700106P31	Composition: 47 ohms ± 5%, 1/8 w.			
		- - - - - NETWORKS - - - - -			
Z502	19C320141P20	Coil.			
		UHS PRE - AMPLIFIER BOARD 19C320215G1 138 - 158 MHz 19C320215G2 147 - 174 MHz			
		- - - - - CAPACITORS - - - - -			
C2301	19A116795P250K	Mica: 250 pF + 10%, 250 VDCW.			
C2302L		(Part of T2301L).			
C2302H		(Part of T2301H).			
C2303 thru C2306	19A116655P19	Ceramic disc: 1000 pF + 20%, 1000 VDCW; sim to RMC Type JF Discap.			
		- - - - - JACKS AND RECEPTACLES - - - - -			
J2301	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF - 1058.			
		- - - - - PLUGS - - - - -			
P2301	19A702402P2	Contact, electrical; sim to AMP 42827 - 2.			
P2302		(Part of W2302).			
		- - - - - TRANSISTORS - - - - -			
Q2301	19A116818P1	N Channel, field effect.			
		- - - - - RESISTORS - - - - -			
R2301	19A700106P39	Composition: 100 ohms ± 5%, 1/8 w.			
R2303	19A700106P87	Composition: 10K ohms ± 5%, 1/8 w.			
R2304	3R152P752J	Composition: 7.5K ohms ± 5%, 1/8 w.			
R2305	3R152P300J	Composition: 30 ohms ± 5%, 1/8 w.			
		- - - - - TRANSFORMERS - - - - -			
T2301L	19C320141P22	Coil.			
T2301H	19C320141P21	Coil.			
T2302	19A127108G1	Coil.			
		- - - - - CABLES - - - - -			
W2302	5491689P85	Cable, RF: approx. 4 inches long. (Includes P2302).			
		- - - - - MISCELLANEOUS - - - - -			
	19B219470P2	Shield.			
	19A701544P8	Can. (Used with L505, L521, Z502 and T2301 on PRE - AMPLIFIER Board).			
	4031594P1	Insulator. (Located under C502, C521).			
	4036306P23	Washer, fiber. (Located under J502).			
	4036306P11	Washer, fiber: 1/8 dia. (Located under Q520).			

SYMBOL	PART NO.	DESCRIPTION
		RECEIVER MODIFICATION KIT 19A129750G1
		- - - - - DIODES AND RECTIFIERS - - - - -
CR2301	19A116925P1	Silicon.
		- - - - - RESISTORS - - - - -
R2301	19A700106P95	Composition: 22K ohms ± 5%, 1/4 w.
R2302	19A700106P59	Composition: 680 ohms ± 5%, 1/4 w.
		- - - - - CABLES - - - - -
W2301	19B219999G2	Cable, RF: approx. 1 foot long. Includes: (1) 5496078P2 connector.
		DFE MODIFICATION KIT 19A129750G2

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Mixer/IF Board 19C331099G1
Transistor Q520 (19A116818P1) is obsolete.
Changed Q520 to 19A116818P4 and added capacitor C531. (19A702236P32) 18 pF from Q520-S to ground.

REV. A thru C - Mixer / IF 19C320153G1

REV. A and B - RF Assembly 19D416693G1_2

REV. A and B - Preamplifier Assembly 19C230215G1_2
Incorporated in initial shipment.

REV. C - RF Assembly 19D416693G2
To improve band end tuning. Changed C306 and C307.

PRODUCTION CHANGES

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- REV. A - Mixer/IF Board 19C331099G1
Transistor Q520 (19A116818P1) is obsolete.
Changed Q520 to 19A116818P4 and added capacitor C531. (19A702236P32) 18 pF from Q520-S to ground.
- REV. A thru C - Mixer/IF 19C320153G1
- REV. A and B - RF Assembly 19D416693G1.2
Incorporated in initial shipment.
- REV. A and B - Preamplifier Assembly 19C230215G1.2
Incorporated in initial shipment.
- REV. C - RF Assembly 19D416693G2
To improve band end tuning. Changed C306 and C307.

NOTE

Variable capacitor C521 does not require adjustment when performing normal alignment. If the four-pole monolithic crystal filter is replaced, then adjustment of C521 is necessary for optimum IF response.

IF Amplifier

IF amplifier Q520 is a dual-gate FET. The filter output is applied to Gate 1 of the amplifier, and the output is taken from the drain. The biasing on Gate 2 and the drain load determines the gain of the stage. The amplifier provides approximately 20 dB of IF gain.

The output of Q520 is coupled through impedance match- ing network L521, and C528 and coupling capacitor C529 and feed-through capacitor C325 to the next IF stage on to the MIF switch in Dual Front End Applications

Supply voltage for the RF amplifier and MIF board is supplied through feed-through capacitor C326.

PARTS LIST

MIF ASSEMBLY

19C331099G1 11.2 MHz IF

19C331099G2 9.4 MHz IF

ISSUE 6

SYMBOL	PART NO.	DESCRIPTION
		----- CAPACITORS -----
C501	19A700233P7	Ceramic: 1000 pF ± 20%, 50 VDCW.
C502	19A700012P2	Variable, ceramic: 2.5 to 20 pF 200 VDCW, temp coef -250 -700 PPM; sim to Panasonic ECXIZW20X32.
C504	19A701624P18	Ceramic, disc: 27 pF ± 5%, 500 VDCW, temp coef, 0 PPM ± 30.
C505A	19A700105P46	Mica: 270 pF ± 5T, 500 VDCW. (Used in G1).
C505B	19A700105P50	Mica: 390 pF ± 5%, 500 VDCW. (Used in G2).
C506	T644ACP310K	Polyester: .010 uF ± 10%, 50 VDCW.
C508	T644ACP322K	Polyester: .022 uF ± 10%, 50 VDCW.
C509	19A701534P8	Tantalum: 22 uF ± 20%, 16 VDCW.
C521	19A700012P1	Variable, ceramic: 2 to 10 pF, 200 VDCW, temp coef -350 to +500 PPM; sim to Panasonic ECV - IZW10X32.
C523		(Part of Z502.)
C524 thru C527	T644ACP322K	Polyester: .022 uF ± 10%, 50 VDCW.
C528A	5490008P139	Silver mica: 330 pf ± 10%, 500 VDCW; sim to Electro Motive Type DM-15. (Used in G1).
C528B	19A700105P50	Mica: 390 pF ± 5%, 500 VDCW. (Used in G2).
C529	19A700233P7	Ceramic: 1000 pF ± 20%, 50 VDCW.
C530	19A700105P17	Mica: 22 pF, 500 VDCW. (Used in G2).
*C531	19A702236P32	Ceramic: 18pF ± 5% temp coef 0 ± 30 PPM/°C.
		----- FILTERS -----
FL501A	19B219573G3	Crystal, freq: Resonator A - 11,200,000 khz, Resonator B - 11,196.024 khz, Resonator A - 11,200,000 khz, Resonator B - 11,196.024 khz. (Used in G1).
FL501B	19B219574G6	Crystal, freq: Resonator A - 9400.000 KHz Resonator B - 9396.024 KHz. (Used in G2).
FL502A		(Part of FL501A). (Used in G1).
FL502B		(Part of FL501B). (Used in G2).
		----- JACKS -----
J501	4033513P1	Contact, electrical: sim to Bead Chain L93 - 4.
J502	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF - 1058.
J523 and J524	19A116975P1	Contact, electrical.
		----- INDUCTORS -----
L501	19A129280P1	Coil.
L502		Coil. (Part of printed wire board).
L504	7488079P48	Coil, RF: 27 uH 10%, 1.4 ohms DC res. max; sim. to Jeffers 4422 - 9.
L505	19C320141P30	Coil.
L506	19A700103P1	Torroidal core.
L520		(Part of Z502).
L521	19C320141P6	Coil.
		----- TRANSISTORS -----
Q501	19A702058P1	N - Channel, field effect; sim to 2N4391.
*Q520	19A116818P4	N Channel, field effect.

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	PART NO.	DESCRIPTION
		----- RESISTORS -----
R501	3R151P471J	Composition: 470 ohms ± 5%, 1/8 w.
R503	19A700106P33	Composition: 56 ohms ± 5%, 1/4 w.
R520	19A700106P87	Composition: 10K ohms ± 5%, 1/4 w.
R521	19A700106P77	Composition: 3.9K ohms ± 5%, 1/4 w.
R522	19A700106P47	Composition: 220 ohms ± 5%, 1/4 w.
R523	19A700106P31	Composition: 47 ohms ± 5%, 1/4 w.
		----- FILTER -----
Z502	19C320141P20	Coil.
		----- MISCELLANEOUS -----
	19B219470P2	Shield.
	19A701544P8	Can, drawn aluminum.
	4031594P1	Insulator.
	4035306P23	Washer, fiber.
	4035306P11	Washer, fiber: 1/8 dia.